

# DATA SHEET

## GENERAL PURPOSE CHIP RESISTORS

RC\_L series

$\pm 0.1\%$ ,  $\pm 0.5\%$ ,  $\pm 1\%$ ,  $\pm 5\%$

Sizes 0075/0100/0201/0402/0603/0805/  
1206/1210/1218/2010/2512

RoHS compliant & Halogen free

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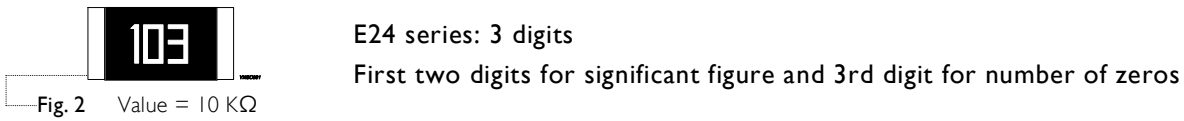


**MARKING**

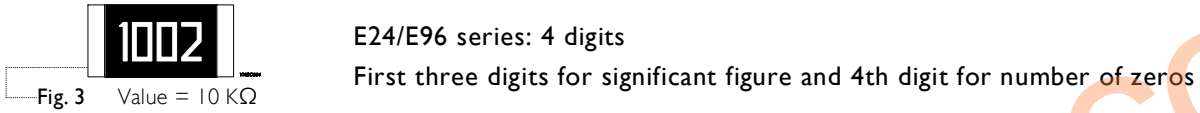
RC0075 / RC0100 / RC0201 / RC0402



RC0603



RC0805 / RC1206 / RC1210 / RC1218 / RC2010 / RC2512



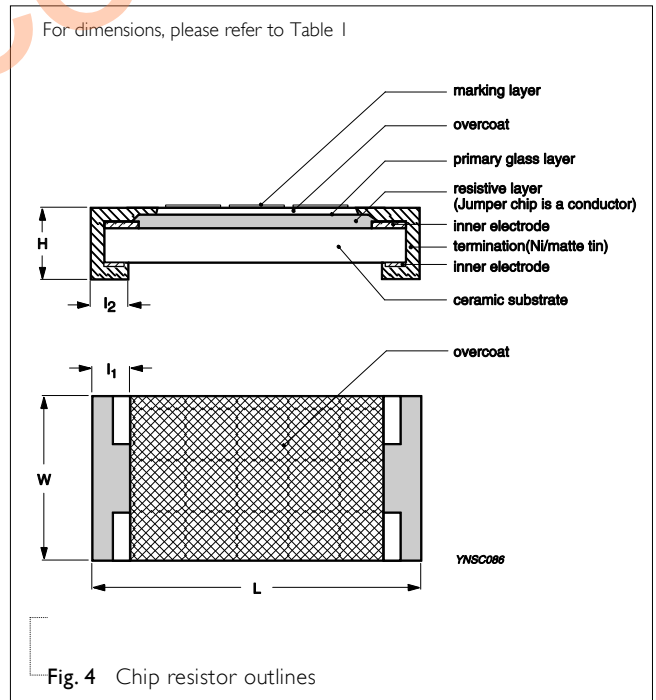
**Note**

For further marking information, please see special data sheet "Chip resistors marking".

**CONSTRUCTION**

The resistor is constructed on top of a high-grade ceramic body. Internal metal electrodes are added on each end to make the contacts to the thick film resistive element. The composition of the resistive element is a noble metal imbedded into a glass and covered by a second glass to prevent environmental influences. The resistor is laser trimmed to the rated resistance value. The resistor is covered with a protective epoxy coat, finally the two external terminations (matte tin on Nibarrier) are added, as shown in Fig.4.

**Outlines**



**DIMENSION**

Table 1

TYPE	L (mm)	W (mm)	H (mm)	l <sub>1</sub> (mm)	l <sub>2</sub> (mm)
RC0075	0.30±0.01	0.15±0.01	0.10±0.01	0.08±0.03	0.08±0.03
RC0100	0.40±0.02	0.20±0.02	0.13±0.02	0.10±0.03	0.10±0.03
RC0201	0.60±0.03	0.30±0.03	0.23±0.03	0.10±0.05	0.15±0.05
RC0402	1.00±0.05	0.50±0.05	0.35±0.05	0.20±0.10	0.25±0.10
RC0603	1.60±0.10	0.80±0.10	0.45±0.10	0.25±0.15	0.25±0.15
RC0805	2.00±0.10	1.25±0.10	0.50±0.10	0.35±0.20	0.35±0.20
RC1206	3.10±0.10	1.60±0.10	0.55±0.10	0.45±0.20	0.40±0.20
RC1210	3.10±0.10	2.60±0.15	0.50±0.10	0.45±0.15	0.50±0.20
RC1218	3.10±0.10	4.60±0.10	0.55±0.10	0.45±0.20	0.40±0.20
RC2010	5.00±0.10	2.50±0.15	0.55±0.10	0.45±0.15	0.50±0.20
RC2512(1W)	6.35±0.10	3.10±0.15	0.55±0.10	0.60±0.20	0.50±0.20
RC2512(2W)	6.35±0.10	3.10±0.15	0.55±0.10	0.60±0.20	1.15±0.20

**ELECTRICAL CHARACTERISTICS**

Table 2

CHARACTERISTICS	POWER	OPERATING TEMPERATURE RANGE	MAXIMUM WORKING VOLTAGE	MAXIMUM OVERLOAD VOLTAGE	DIELECTRIC WITHSTANDING VOLTAGE	RESISTANCE RANGE	TEMPERATURE COEFFICIENT	JUMPER CRITERIA
RC0075	1/50 W	-55°C to 125°C	10V	25V	25V	5% (E24) 10Ω≤R≤1MΩ 1% (E24/E96) 10Ω≤R≤1MΩ Jumper<50mΩ	10Ω≤R<100Ω -200~+600ppm/°C 100Ω≤R≤1MΩ ±200ppm/°C	Rated Current 0.5A Maximum Current 1.0A
RC0100	1/32 W	-55°C to 125°C	15V	30V	30V	5% (E24) 1Ω≤R≤22MΩ 1% (E24/E96) 1Ω≤R≤10MΩ 0.5% (E24/E96) 33Ω≤R≤470KΩ Jumper<50mΩ	1Ω≤R<10Ω -200~+600ppm/°C 10Ω≤R<100Ω: ±300ppm/°C 100Ω≤R≤10MΩ: ±200ppm/°C 10MΩ<R≤22MΩ: ±250ppm/°C	Rated Current 0.5A Maximum Current 1.0A
RC0201	1/20 W	-55°C to 125°C	25V	50V	50V	5% (E24) 1Ω≤R≤10MΩ 1% (E24/E96) 1Ω≤R≤10MΩ 0.1%, 0.5% (E24/E96) 10Ω≤R≤1MΩ Jumper<50mΩ	1Ω≤R≤10Ω -100~+350ppm/°C 10Ω<R≤10MΩ ±200ppm/°C	Rated Current 0.5A Maximum Current 1.0A
RC0402	1/16 W	-55°C to 155°C	50V	100V	100V	5% (E24) 1Ω≤R≤22MΩ 1% (E24/E96) 1Ω≤R≤10MΩ 0.1%, 0.5% (E24/E96) 10Ω≤R≤1MΩ Jumper<50mΩ	1Ω≤R≤10Ω ±200ppm/°C 10Ω<R≤10MΩ ±100ppm/°C 10MΩ<R≤22MΩ ±200ppm/°C	Rated Current 1.0A Maximum Current 2.0A
	1/8W	-55°C to 155°C	50V	100V	100V	5% (E24) 1Ω≤R≤1MΩ 1% (E24/E96) 1Ω≤R≤1MΩ	1Ω≤R≤10Ω ±200ppm/°C	

Table 2

CHARACTERISTICS	POWER	OPERATING TEMPERATURE RANGE	MAXIMUM WORKING VOLTAGE	MAXIMUM OVERLOAD VOLTAGE	DIELECTRIC WITHSTANDING VOLTAGE	RESISTANCE RANGE	TEMPERATURE COEFFICIENT	JUMPER CRITERIA
RC0603	1/10 W	-55°C to 155°C	75V	150V	150V	5% (E24) 1Ω ≤ R ≤ 22MΩ 1% (E24/E96) 1Ω ≤ R ≤ 10MΩ 0.1%, 0.5% (E24/E96) 10Ω ≤ R ≤ 1MΩ Jumper < 50mΩ	1Ω ≤ R ≤ 10Ω ±200ppm°C 10Ω < R ≤ 10MΩ ±100ppm°C 10MΩ < R ≤ 22MΩ ±200ppm°C	Rated Current 1.0A Maximum Current 2.0A
	1/5 W	-55°C to 155°C	75V	150V	150V	5% (E24) 1Ω ≤ R ≤ 1MΩ 1% (E24/E96) 1Ω ≤ R ≤ 1MΩ	1Ω ≤ R ≤ 1MΩ ±200ppm°C	
RC0805	1/8 W	-55°C to 155°C	150V	300V	300V	5% (E24) 1Ω ≤ R ≤ 22MΩ 1% (E24/E96) 1Ω ≤ R ≤ 10MΩ 0.1%, 0.5% (E24/E96) 10Ω ≤ R ≤ 1MΩ 5%, 10%, 20% (E24) 24MΩ ≤ R ≤ 100MΩ Jumper < 50mΩ	1Ω ≤ R ≤ 10Ω ±200ppm°C 10Ω < R ≤ 10MΩ ±100ppm°C 10MΩ < R ≤ 22MΩ ±200ppm°C 24MΩ < R ≤ 100MΩ ±300ppm°C	Rated Current 2.0A Maximum Current 5.0A
	1/4 W	-55°C to 155°C	150V	300V	300V	5% (E24) 1Ω ≤ R ≤ 1MΩ 1% (E24/E96) 1Ω ≤ R ≤ 1MΩ	1Ω ≤ R ≤ 1MΩ ±200ppm°C	
RC1206	1/4 W	-55°C to 155°C	200V	400V	500V	5% (E24) 1Ω ≤ R ≤ 22MΩ 1% (E24/E96) 1Ω ≤ R ≤ 10MΩ 0.1%, 0.5% (E24/E96) 10Ω ≤ R ≤ 1MΩ 5%, 10%, 20% (E24) 24MΩ ≤ R ≤ 100MΩ Jumper < 50mΩ	1Ω ≤ R ≤ 10Ω ±200ppm°C 10Ω < R ≤ 10MΩ ±100ppm°C 10MΩ < R ≤ 22MΩ ±200ppm°C 24MΩ < R ≤ 100MΩ ±300ppm°C	Rated Current 2.0A Maximum Current 10.0A
	1/2 W	-55°C to 155°C	200V	400V	500V	5% (E24) 1Ω ≤ R ≤ 1MΩ 1% (E24/E96) 1Ω ≤ R ≤ 1MΩ	1Ω ≤ R ≤ 1MΩ ±200ppm°C	
RC1210	1/2 W	-55°C to 155°C	200V	500V	500V	5% (E24) 1Ω ≤ R ≤ 22MΩ 1% (E24/E96) 1Ω ≤ R ≤ 10MΩ 0.1%, 0.5% (E24/E96) 10Ω ≤ R ≤ 1MΩ Jumper < 50mΩ	1Ω ≤ R ≤ 10Ω ±200ppm°C 10Ω < R ≤ 10MΩ ±100ppm°C 10MΩ < R ≤ 22MΩ ±200ppm°C	Rated Current 2.0A Maximum Current 10.0A
RC1218	1 W	-55°C to 155°C	200V	500V	500V	5% (E24) 1Ω ≤ R ≤ 1MΩ 1% (E24/E96) 1Ω ≤ R ≤ 1MΩ 0.1%, 0.5% (E24/E96) 10Ω ≤ R ≤ 1MΩ Jumper < 50mΩ	1Ω ≤ R ≤ 10Ω ±200ppm°C 10Ω < R ≤ 1MΩ ±100ppm°C	Rated Current 6.0A Maximum Current 10.0A

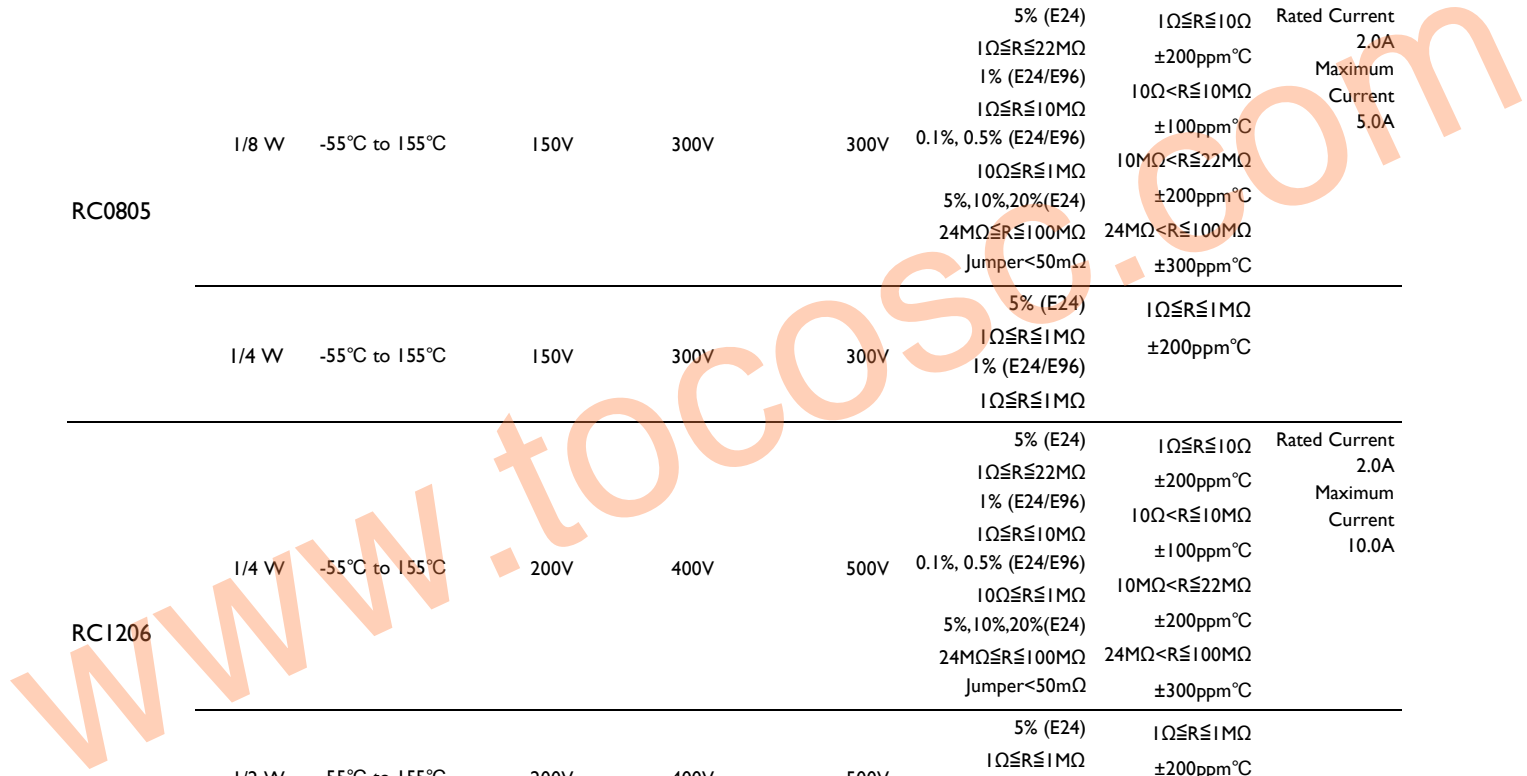
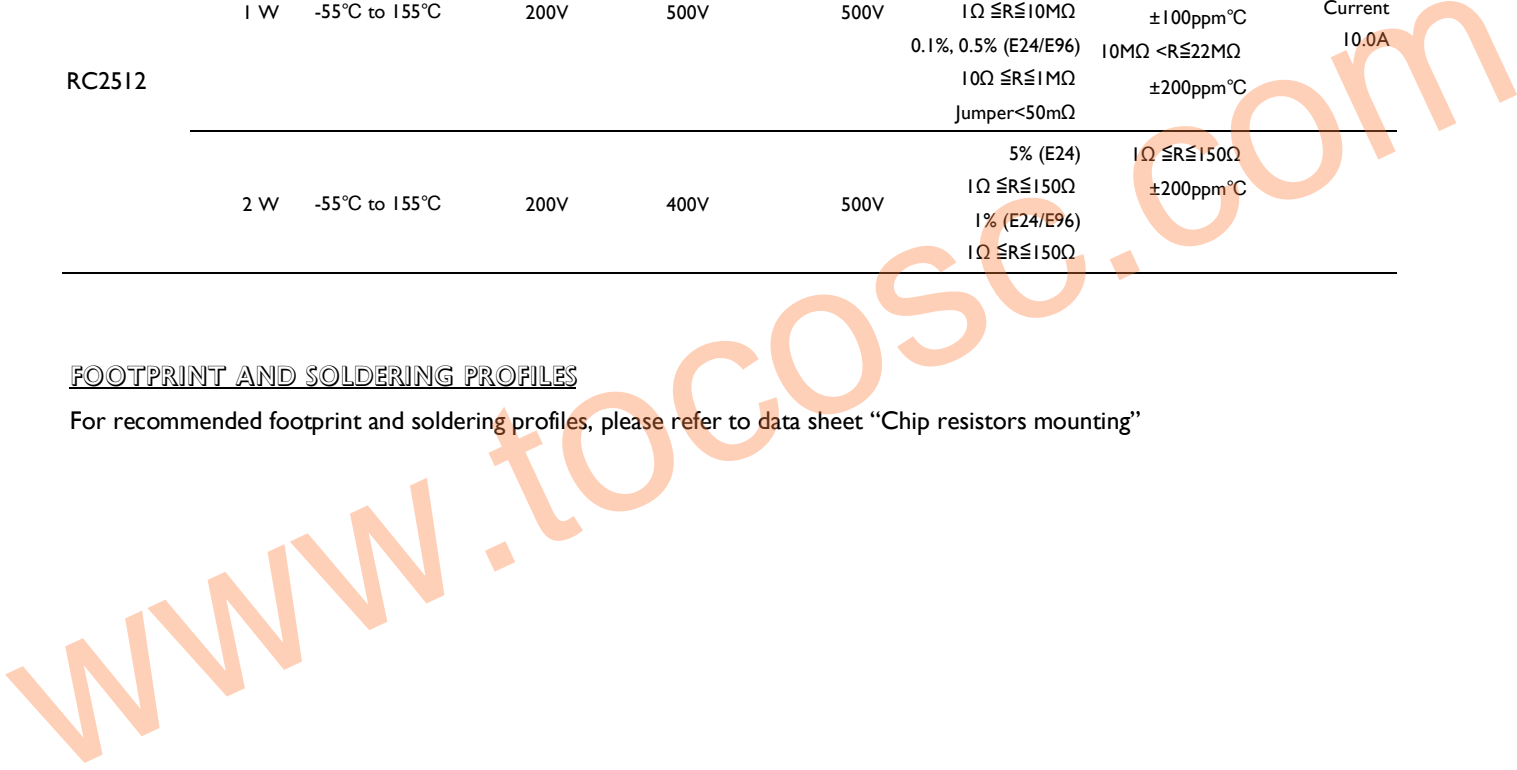


Table 2

CHARACTERISTICS	POWER	OPERATING TEMPERATURE RANGE	MAXIMUM WORKING VOLTAGE	MAXIMUM OVERLOAD VOLTAGE	DIELECTRIC WITHSTANDING VOLTAGE	RESISTANCE RANGE	TEMPERATURE COEFFICIENT	JUMPER CRITERIA
RC2010	3/4 W	-55°C to 155°C	200V	500V	500V	5% (E24) $1\Omega \leq R \leq 22M\Omega$	$1\Omega \leq R \leq 10\Omega$ $\pm 200\text{ppm}^\circ\text{C}$	Rated Current 2.0A
						1% (E24/E96) $1\Omega \leq R \leq 10M\Omega$	$10\Omega < R \leq 10M\Omega$ $\pm 100\text{ppm}^\circ\text{C}$	Maximum Current 10.0A
RC2512	1 W	-55°C to 155°C	200V	500V	500V	0.1%, 0.5% (E24/E96) $10\Omega \leq R \leq 1M\Omega$	$10M\Omega < R \leq 22M\Omega$ $\pm 200\text{ppm}^\circ\text{C}$	Rated Current 2.0A
						1% (E24/E96) $1\Omega \leq R \leq 10M\Omega$	$10\Omega < R \leq 10M\Omega$ $\pm 100\text{ppm}^\circ\text{C}$	Maximum Current 10.0A
						Jumper < 50mΩ	$10M\Omega < R \leq 22M\Omega$ $\pm 200\text{ppm}^\circ\text{C}$	
	2 W	-55°C to 155°C	200V	400V	500V	5% (E24) $1\Omega \leq R \leq 150\Omega$	$1\Omega \leq R \leq 150\Omega$ $\pm 200\text{ppm}^\circ\text{C}$	
						1% (E24/E96) $1\Omega \leq R \leq 150\Omega$		

**FOOTPRINT AND SOLDERING PROFILES**

For recommended footprint and soldering profiles, please refer to data sheet “Chip resistors mounting”



**PACKING STYLE AND PACKAGING QUANTITY**

Table 3 Packing style and packaging quantity

PACKING STYLE	PAPER TAPING REEL (R)		ESD SAFE REEL (S) (4MM WIDTH, 1MM PITCH PLASTIC EMBOSSD)	EMBOSSD TAPING REEL
REEL DIMENSION	7" (178 mm)	13" (330 mm)	7" (178 mm)	7" (178 mm)
RC0075	---	---	40,000	---
RC0100	20,000	80,000	40,000	---
RC0201	10,000	50000	---	---
RC0402	10,000	50000	---	---
RC0603	5,000	20000	---	---
RC0805	5,000	20000	---	---
RC1206	5,000	20000	---	---
RC1210	5,000	20000	---	---
RC1218	---	---	---	4,000
RC2010	---	---	---	4,000
RC2512	---	---	---	4,000

**NOTE**

For tape and reel specification/dimensions, please refer to data sheet "Chip resistors packing".

**FUNCTIONAL DESCRIPTION**

**OPERATING TEMPERATURE RANGE**

RC0402 to RC2512 Range: -55°C to +155°C (Fig. 5-1)

RC0075 to RC0201 Range: -55°C to +125°C (Fig. 5-2)

**POWER RATING**

Each type rated power at 70 °C:

- RC0075=1/50W
- RC0100=1/32W
- RC0201=1/20W
- RC0402=1/16W, 1/8W
- RC0603=1/10W, 1/5W
- RC0805=1/8W, 1/4W
- RC1206=1/4W, 1/2W
- RC1210=1/2W
- RC1218=1W
- RC2010=3/4W
- RC2512=1W, 2W

**RATED VOLTAGE**

The DC or AC (rms) continuous working voltage corresponding to the rated power is determined by the following formula:

$$V = \sqrt{(PxR)}$$

Where

V = Continuous rated DC or AC (rms) working voltage (V)

P = Rated power (W)

R = Resistance value (Ω)

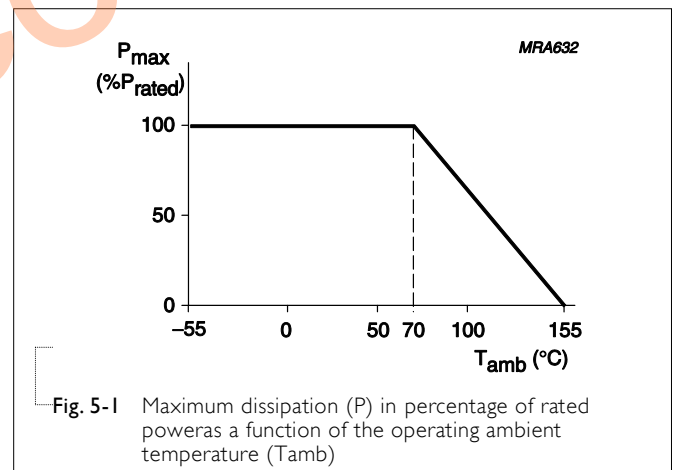


Fig. 5-1 Maximum dissipation (P) in percentage of rated power as a function of the operating ambient temperature (T<sub>amb</sub>)

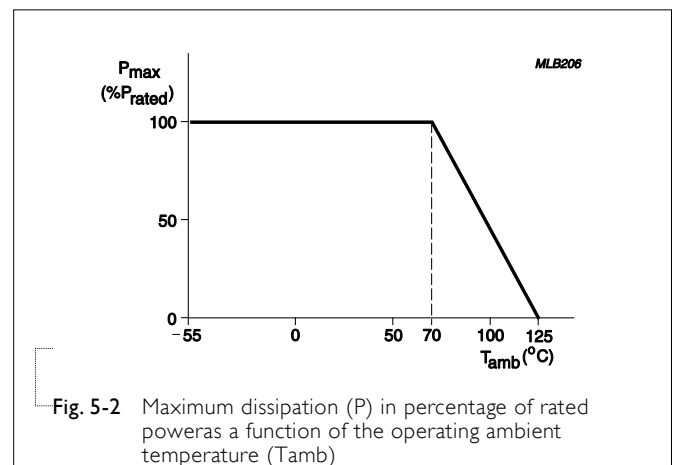


Fig. 5-2 Maximum dissipation (P) in percentage of rated power as a function of the operating ambient temperature (T<sub>amb</sub>)

**TESTS AND REQUIREMENTS**

Table 8 Test condition, procedure and requirements

TEST	TEST METHOD	PROCEDURE	REQUIREMENTS
Temperature Coefficient of Resistance (T.C.R.)	IEC 60115-1 4.8	At +25/-55 °C and +25/+125 °C  Formula: $T.C.R = \frac{R_2 - R_1}{R_1(t_2 - t_1)} \times 10^6 \text{ (ppm/°C)}$ Where t <sub>1</sub> =+25 °C or specified room temperature t <sub>2</sub> =-55 °C or +125 °C test temperature R <sub>1</sub> =resistance at reference temperature in ohms R <sub>2</sub> =resistance at test temperature in ohms	Refer to table 2
Life/ Endurance	MIL-STD-202G Method 108A IEC 60115-1 4.25.1	At 70±5°C for 1,000 hours; RCWV applied for 1.5 hours on and 0.5 hour off, still air required	±(1%+0.05Ω) for D/F tol ±(3%+0.05Ω) for J tol <100mR for jumper
High Temperature Exposure	MIL-STD-202G Method 108A IEC 60115-1 4.25.3	1,000 hours at maximum operating temperature depending on specification, unpowered.	±(1%+0.05Ω) for D/F tol ±(2%+0.05Ω) for J tol <50mR for jumper
Moisture Resistance	MIL-STD-202G Method 106F IEC 60115-1 4.24.2	Each temperature / humidity cycle is defined at 8 hours (method 106F), 3 cycles / 24 hours for 10d with 25 °C / 65 °C 95% R.H, without steps 7a & 7b, unpowered Parts mounted on test-boards, without condensation on parts	±(0.5%+0.05Ω) for D/F tol ±(2%+0.05Ω) for J tol <100mR for jumper
Humidity	IEC 60115-1 4.37	Steady state for 1000 hours at 40 °C / 95% R.H. RCWV applied for 1.5 hours on and 0.5 hour off	±(1%+0.05Ω) for D/F tol ±(2%+0.05Ω) for J tol <100mR for jumper
Thermal Shock	MIL-STD-202G Method 107G	-55/+125°C Note Number of cycles required is 300 Devices unmounted Maximum transfer time is 20 seconds Dwell time is 15 minutes. Air - Air	±(0.5%+0.05Ω) for D/F tol ±(1%+0.05Ω) for J tol <50mR for jumper
Short Time Overload	IEC 60115-1 4.13	2.5 times RCWV or maximum overload voltage which is less for 5 seconds at room temperature	±(1%+0.05Ω) for D/F tol ±(2%+0.05Ω) for J tol <50mR for jumper No visible damage
Board Flex/ Bending	IEC 60115-1 4.33	Device mounted or as described only 1 board bending required bending time: 60±5 seconds 0075/0100/0201/0402:5mm; 0603/0805:3mm; 1206 and above:2mm	±(1%+0.05Ω) for D/F/J Tol <50mR for jumper No visible damage



TEST	TEST METHOD	PROCEDURE	REQUIREMENTS
Solderability - Wetting	IPC/JEDECJ-STD-002B test B IEC 60068-2-58	Electrical Test not required Magnification 50X SMD conditions: 1st step: method B, aging 4 hours at 155 °C dry heat 2nd step: leadfree solder bath at 245±3 °C Dipping time: 3±0,5 seconds	Well tinned (>95% covered) No visible damage
-Leaching	IPC/JEDECJ-STD-002B test D IEC 60068-2-58	Leadfree solder ,260°C, 30 seconds immersion time	No visible damage
-Resistance to Soldering Heat	MIL-STD-202F Method 210F IEC 60068-2-58	Condition B, no pre-heat of samples Leadfree solder, 260 °C ±5°C, 10 ±1 seconds immersion time Procedure 2 for SMD: devices fluxed and cleaned with isopropanol	±(0,5%+0,05Ω ) for D/F tol ±(1%+0,05Ω ) for J tol <50mR for jumper No visible damage

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REVISION HISTORY

REVISION	DATE	CHANGE NOTIFICATION	DESCRIPTION
Version 0	Aug. 29, 2014	-	- First issue of this specification

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